TOSHIBA GTR Module Silicon N Channel IGBT

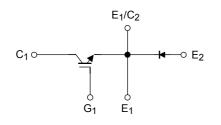
MG150J1JS50

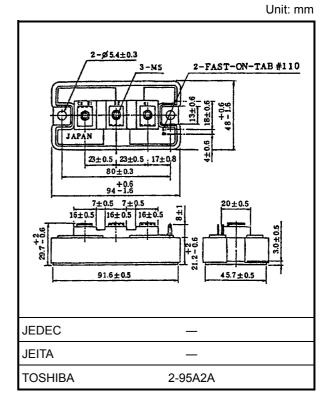
High Power Switching Applications Motor Control Applications

- The electrodes are isolated from case.
- High input impedance
- Includes a complete half bridge in one package.
- Enhancement-mode
- High speed : $t_f = 0.30 \ \mu s \ (max) \ (I_C = 150 \ A)$ $t_{rr} = 0.15 \ \mu s \ (max) \ (I_F = 150 \ A)$
- Low saturation voltage

 $: V_{CE} (sat) = 2.70 V (max) (I_{C} = 150 A)$

Equivalent Circuit





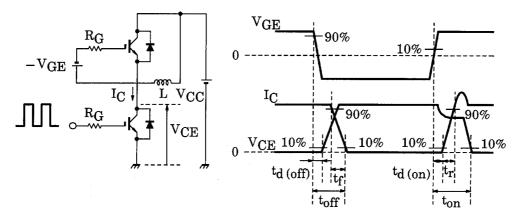
Maximum Ratings (Ta = 25°C)

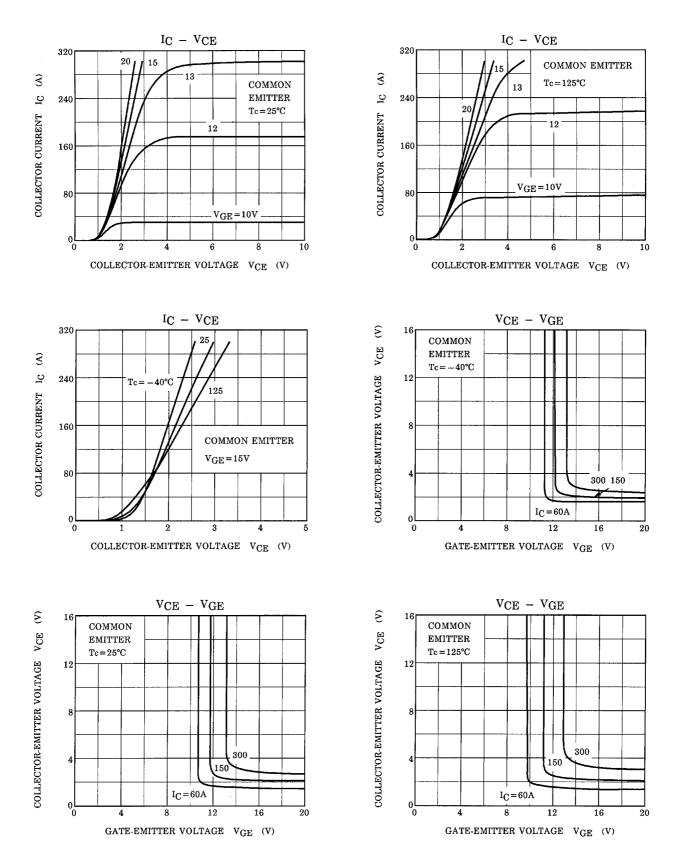
Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V _{GES}	±20	V	
Reverse voltage		V _R	600	V	
Collector current	DC	Ι _C	150	A	
	1 ms	I _{CP}	300		
Forward current	DC	١ _F	150	A	
	1 ms	I _{FM}	300		
Collector power dissipation (Tc = 25°C)		PC	780	W	
Junction temperature		Тj	150	°C	
Storage temperature range		T _{stg}	-40 to 125	°C	
Isolation voltage		V _{lsol}	2500 (AC 1 min.)	V	
Screw torque (Terminal/mounting)		_	3/3	N∙m	

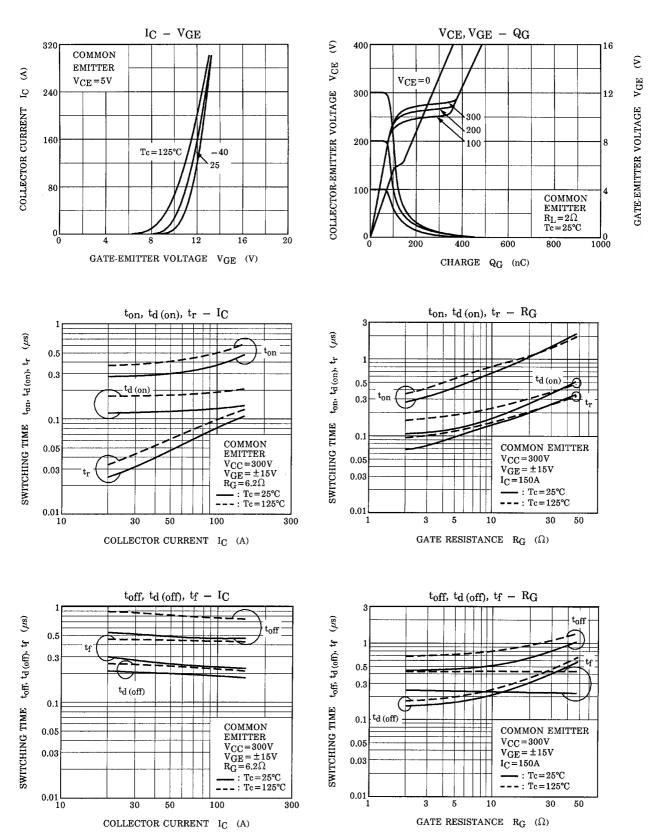
Electrical Characteristics (Ta = 25°C)

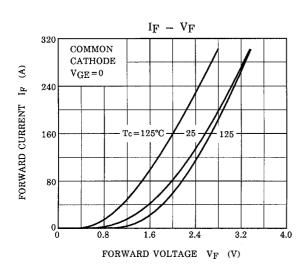
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	$V_{GE} = \pm 20 \text{ V}, V_{CE} = 0$	_	—	±500	nA
Collector cut-off current		ICES	V _{CE} = 600 V, V _{GE} = 0	_	_	2.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 15 mA, V _{CE} = 5 V	5.0	7.0	8.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 150 A,V _{GE} = 15 V	_	2.10	2.70	V
Input capacitance		Cies	V _{CE} = 10 V, V _{GE} = 0, f = 1 MHz	_	14200	_	pF
Switching time	Turn-on delay time	t _{d (on)}	Inductive load $V_{CC} = 300 V$ $I_C = 150 A$ $V_{GE} = \pm 15 V$ $R_G = 6.2 \Omega$ (Note 1)	_	0.15	0.30	μs
	Rise time	t _r		_	0.15	0.30	
	Turn-on time	t _{on}		_	0.50	1.00	
	Turn-off delay time	t _{d (off)}		_	0.20	0.40	
	Fall time	t _f		_	0.15	0.30	
	Turn-off time	t _{off}		_	0.50	1.00	
Reverse current	·	I _R	V _R = 600 V	_	_	1.0	mA
Forward voltage		V _F	I _F = 150 A, V _{GE} = 0	_	2.30	3.00	V
Reverse recovery time t		t _{rr}	I _F = 150 A, V _{GE} = −10 V di/dt = 200 A/μs	_	0.08	0.15	μs
Thermal resistance		R _{th (j-c)}	Transistor stage	_	_	0.16	°C/W
			Diode stage	_	_	0.35	

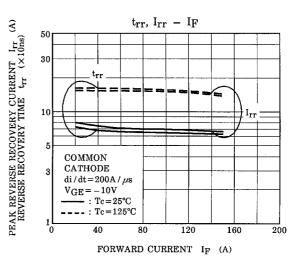
Note 1: Switching time test circuit & timing chart

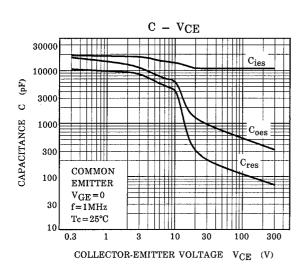




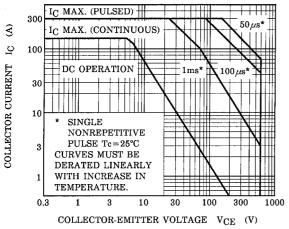


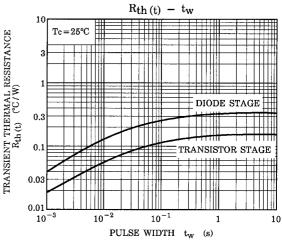


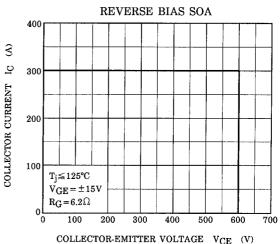


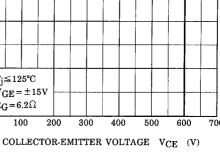


SAFE OPERATING AREA









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